

Isc N-Channel MOSFET Transistor

STP80NF55-06

• FEATURES

- Typical $R_{DS(on)}=0.005\ \Omega$
- Excellent switching performance
- Easy to drive
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

• APPLICATIONS

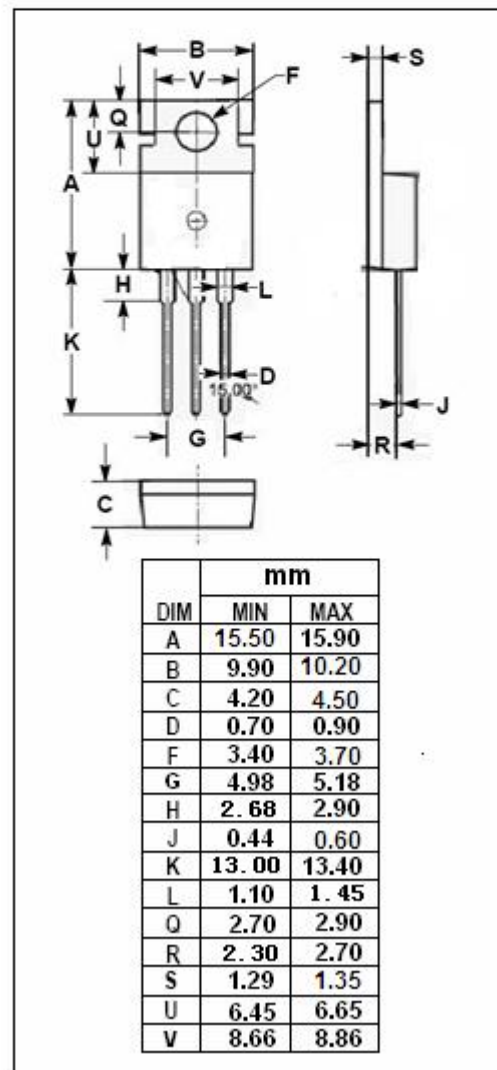
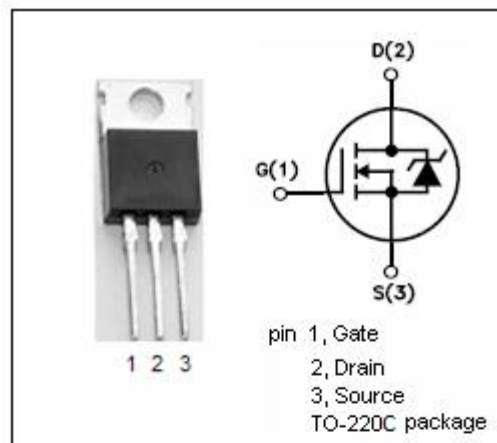
- Solenoid and relay drivers
- DC-DC converters
- Automotive environment

• ABSOLUTE MAXIMUM RATINGS($T_a=25^\circ\text{C}$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{DSS}	Drain-Source Voltage	55	V
V_{GSS}	Gate-Source Voltage	± 20	V
I_D	Drain Current-Continuous@ $T_c=25^\circ\text{C}$ $T_c=100^\circ\text{C}$	80 57	A
I_{DM}	Drain Current-Single Pulsed	320	A
P_D	Total Dissipation	210	W
T_j	Max. Operating Junction Temperature	175	$^\circ\text{C}$
T_{stg}	Storage Temperature	-55~175	$^\circ\text{C}$

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th(ch-c)}$	Channel-to-case thermal resistance	0.7	$^\circ\text{C/W}$
$R_{th(ch-a)}$	Channel-to-ambient thermal resistance	62.5	$^\circ\text{C/W}$



Isc N-Channel MOSFET Transistor**STP80NF55-06****ELECTRICAL CHARACTERISTICS****T_C=25°C unless otherwise specified**

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 0.25mA	55			V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =±20V; I _D =0.25mA	2		4	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D =40A			6.5	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±20V; V _{DS} = 0V			±0.1	μA
I _{DSS}	Drain-Source Leakage Current	V _{DS} = 55V; V _{GS} = 0V; T _J =25°C T _J =125°C			1 10	μA
V _{SD}	Diode forward voltage	I _{SD} =80A, V _{GS} = 0 V			1.5	V

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